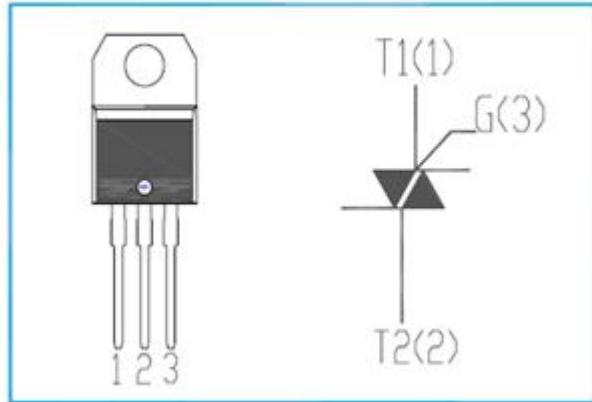


## 12A Standard Triacs

**FEATURES**

- With TO-220 package
- Glass passivated triacs in a plastic envelope, Intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all our quadrants.
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**ABSOLUTE MAXIMUM RATINGS(Ta=25°C)**

SYMBOL	PARAMETER	MIN	UNIT
$V_{DRM}$	Repetitive peak off-state voltage	800	V
$V_{RRM}$	Repetitive peak off-state voltage	800	V
$I_{T(RMS)}$	RMS on-state current (full sine wave)	12	A
$I_{TSM}$	Non-repetitive peak on-state current	95	A
$P_{GM}$	Peak gate power dissipation	5	W
$P_{G(AV)}$	Average gate power dissipation	0.5	W
$T_j$	Operating junction temperature	125	°C
$T_{stg}$	Storage temperature	-45~150	°C

**ELECTRICAL CHARACTERISTICS (Tc=25°C unless otherwise specified)**

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$I_{RRM}$	Repetitive peak reverse current	$V_R=V_{RRM}$ , $V_R=V_{RRM}$ , $T_j=125^\circ C$	0.02 0.5		mA
$I_{DRM}$	Repetitive peak off-state current	$V_D=V_{DRM}$ , $V_D=V_{DRM}$ , $T_j=125^\circ C$	0.02 0.5		mA
$I_{GT}$	Gate trigger current	I	$V_D=12V$ ; $I_T= 0.1A$ , $R_L= 30 \Omega$	5	mA
		II		5	
		III		5	
		IV		10	
$V_{TM}$	On-state voltage	$I_T= 15A$		1.65	V
$I_H$	Holding current	$I_{GT}= 0.1A$ , $V_D= 12V$		35	mA
$V_{GT}$	Gate trigger voltage	$V_D=12V$ ; $R_L= 30 \Omega$ all quadrant		1.5	V